# **4-Bit Dual-Supply Inverting** Level Translator

The NLSV4T240 is a 4-bit configurable dual-supply voltage level translator. The input  $A_n$  and output  $B_n$  ports are designed to track two different power supply rails,  $V_{CCA}$  and  $V_{CCB}$  respectively. Both supply rails are configurable from 0.9 V to 4.5 V allowing universal low-voltage translation from the input  $A_n$  to the output  $B_n$  port.

## Features

- Wide  $V_{CCA}$  and  $V_{CCB}$  Operating Range: 0.9 V to 4.5 V
- High-Speed w/ Balanced Propagation Delay
- Inputs and Outputs have OVT Protection to 4.5 V
- Non-preferential V<sub>CCA</sub> and V<sub>CCB</sub> Sequencing
- Outputs at 3-State until Active V<sub>CC</sub> is Reached
- Power-Off Protection
- Outputs Switch to 3-State with V<sub>CCB</sub> at GND
- Ultra-Small Packaging: 1.7 mm x 2.0 mm UQFN12
- This is a Pb-Free Device

## **Typical Applications**

• Mobile Phones, PDAs, Other Portable Devices

## Important Information

• ESD Protection for All Pins: HBM (Human Body Model) > 6000 V

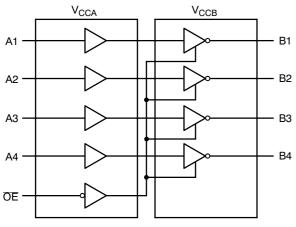


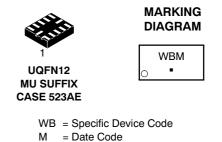
Figure 1. Logic Diagram

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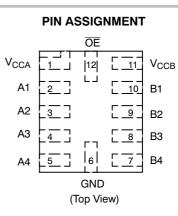


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= Pb-Free Package



#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NLSV4T240MUTAG	UQFN12 (Pb-Free)	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

## **PIN ASSIGNMENT**

PIN	FUNCTION
V <sub>CCA</sub>	Input Port DC Power Supply
V <sub>CCB</sub>	Output Port DC Power Supply
GND	Ground
A <sub>n</sub>	Input Port
B <sub>n</sub>	Output Port
ŌE	Output Enable

#### TRUTH TABLE

In	Inputs				
ŌE	A <sub>n</sub>	B <sub>n</sub>			
L	L	Н			
L	Н	L			
н	х	3-State			

## MAXIMUM RATINGS

Symbol	Rating		Value	Condition	Unit
V <sub>CCA</sub> , V <sub>CCB</sub>	DC Supply Voltage		-0.5 to +5.5		V
VI	DC Input Voltage	A <sub>n</sub>	-0.5 to +5.5		V
V <sub>C</sub>	Control Input	OE	-0.5 to +5.5		V
V <sub>O</sub>	DC Output Voltage (Power Down)	B <sub>n</sub>	-0.5 to +5.5	$V_{CCA} = V_{CCB} = 0$	V
	(Active Mode)	B <sub>n</sub>	-0.5 to +5.5		V
	(Tri-State Mode)	B <sub>n</sub>	-0.5 to +5.5		V
I <sub>IK</sub>	DC Input Diode Current		-20	V <sub>I</sub> < GND	mA
Ι <sub>ΟΚ</sub>	DC Output Diode Current		-50	V <sub>O</sub> < GND	mA
Ι <sub>Ο</sub>	DC Output Source/Sink Current		±50		mA
I <sub>CCA</sub> , I <sub>CCB</sub>	DC Supply Current Per Supply Pin		±100		mA
I <sub>GND</sub>	DC Ground Current per Ground Pin		±100		mA
T <sub>STG</sub>	Storage Temperature		-65 to +150		°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

## **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter		Min	Мах	Unit
$V_{CCA}, V_{CCB}$	Positive DC Supply Voltage		0.9	4.5	V
VI	Bus Input Voltage		GND	4.5	V
V <sub>C</sub>	Control Input	ŌE	GND	4.5	V
V <sub>IO</sub>	Bus Output Voltage (Power Down Mode)	B <sub>n</sub>	GND	4.5	V
	(Active Mode)	B <sub>n</sub>	GND	V <sub>CCB</sub>	V
	(Tri-State Mode)	B <sub>n</sub>	GND	4.5	V
T <sub>A</sub>	Operating Temperature Range		-40	+85	°C
$\Delta t / \Delta V$	Input Transition Rise or Rate V <sub>I</sub> , from 30% to 70% of V <sub>CC</sub> ; V <sub>CC</sub> = 3.3 V $\pm 0.3$ V		0	10	nS

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## DC ELECTRICAL CHARACTERISTICS

					-40°C te	o +85°C	
Symbol	Parameter	Test Conditions	V <sub>CCA</sub> (V)	V <sub>CCB</sub> (V)	Min	Max	Uni
V <sub>IH</sub>	Input HIGH Voltage		3.6 - 4.5	0.9 - 4.5	2.2	-	V
	(An, OE)		2.7 – 3.6		2.0	-	
			2.3 – 2.7		1.6	-	
			1.4 - 2.3		0.65 * V <sub>CCA</sub>	-	
			0.9 - 1.4		0.9 * V <sub>CCA</sub>	-	
VIL	Input LOW Voltage		3.6 – 4.5	0.9 - 4.5	-	0.8	V
	(An, OE)		2.7 – 3.6		-	0.8	
			2.3 – 2.7		-	0.7	
			1.4 - 2.3		-	0.35 * V <sub>CCA</sub>	
			0.9 – 1.4		-	0.1 * V <sub>CCA</sub>	
V <sub>OH</sub>	Output HIGH Voltage	$I_{OH}$ = -100 $\mu$ A; V <sub>I</sub> = V <sub>IH</sub>	0.9 - 4.5	0.9 - 4.5	V <sub>CCB</sub> - 0.2	-	V
		$I_{OH}$ = -0.5 mA; $V_I$ = $V_{IH}$	0.9	0.9	0.75 * V <sub>CCB</sub>	-	
		$I_{OH} = -2 \text{ mA}; V_I = V_{IH}$	1.4	1.4	1.05	-	
		$I_{OH} = -6 \text{ mA}; V_I = V_{IH}$	1.65	1.65	1.25	-	
			2.3	2.3	2.0	-	
		$I_{OH} = -12 \text{ mA}; V_I = V_{IH}$	2.3	2.3	1.8	-	
			2.7	2.7	2.2	-	
		I <sub>OH</sub> = -18 mA; V <sub>I</sub> = V <sub>IH</sub>	2.3	2.3	1.7	-	
			3.0	3.0	2.4	-	
		$I_{OH}$ = -24 mA; $V_I$ = $V_{IH}$	3.0	3.0	2.2	-	
V <sub>OL</sub>	Output LOW Voltage	$I_{OL} = 100 \ \mu A; \ V_I = V_{IL}$	0.9-4.5	0.9 - 4.5	-	0.2	V
		$I_{OL}$ = 0.5 mA; $V_I$ = $V_{IH}$	1.1	1.1	-	0.3	
		$I_{OL}$ = 2 mA; $V_I$ = $V_{IH}$	1.4	1.4	-	0.35	
		$I_{OL} = 6 \text{ mA}; V_I = V_{IL}$	1.65	1.65	-	0.3	
		$I_{OL} = 12 \text{ mA}; V_I = V_{IL}$	2.3	2.3	-	0.4	
			2.7	2.7	-	0.4	
		I <sub>OL</sub> = 18 mA; V <sub>I</sub> = V <sub>IL</sub>	2.3	2.3	-	0.6	
			3.0	3.0	-	0.4	
		$I_{OL}$ = 24 mA; $V_I$ = $V_{IL}$	3.0	3.0	-	0.55	
I <sub>I</sub>	Input Leakage Current	$V_I = V_{CCA}$ or GND	0.9 - 4.5	0.9 - 4.5	-1.0	1.0	μA
I <sub>OFF</sub>	Power-Off Leakage Current	<u>OE</u> = 0 V	0 0.9 – 4.5	0.9 – 4.5 0	-1.0 -1.0	1.0 1.0	μA
I <sub>CCA</sub>	Quiescent Supply Current		0.9 - 4.5	0.9 - 4.5	-	2.0	μA
I <sub>CCB</sub>	Quiescent Supply Current		0.9 - 4.5	0.9 - 4.5	-	2.0	μ
CCA + I <sub>CCB</sub>	Quiescent Supply Current		0.9 – 4.5	0.9 – 4.5	-	4.0	μA
∆l <sub>CCA</sub> aSheet4U.	Increase in $I_{CC}$ per Input Voltage, Other Inputs at $V_{CCA}$ or GND	$V_{I} = V_{CCA} - 0.6 V;$ $V_{I} = V_{CCA} \text{ or GND}$	4.5 3.6	4.5 3.6	-	10 5.0	μ
$\Delta I_{CCB}$	Increase in $I_{CC}$ per Input Voltage, Other Inputs at $V_{CCA}$ or GND	$V_{I} = V_{CCA} - 0.6 V;$ $V_{I} = V_{CCA}$ or GND	4.5 3.6	4.5 3.6	-	10 5.0	μA
I <sub>OZ</sub>	I/O Tri-State Output Leakage Current	$T_A = 25^{\circ}C, \overline{OE} = 0 V$	0.9-4.5	0.9-4.5	-1.0	1.0	μ/

## TOTAL STATIC POWER CONSUMPTION (I<sub>CCA</sub> + I<sub>CCB</sub>)

					–40°C t	o +85°C					
					V <sub>CC</sub>	<sub>B</sub> (V)					1
	4.5 3.3 2.8 1.8			.8	0.9		1				
V <sub>CCA</sub> (V)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
4.5		2		2		2		2		< 1.5	μA
3.3		2		2		2		2		< 1.5	μA
2.8		< 2		< 1		< 1		< 0.5		< 0.5	μA
1.8		< 1		< 1		< 0.5		< 0.5		< 0.5	μA
0.9		< 0.5		< 0.5		< 0.5		< 0.5		< 0.5	μA

NOTE: Connect ground before applying supply voltage V<sub>CCA</sub> or V<sub>CCB</sub>. This device is designed with the feature that the power-up sequence of  $V_{CCA}$  and  $V_{CCB}$  will not damage the IC.

## **AC ELECTRICAL CHARACTERISTICS**

							–40°C t	o +85°C					
							Vcc	<sub>в</sub> (V)					
			4	.5	3	.3	2	.8	1	.8	1	.2	
Symbol	Parameter	V <sub>CCA</sub> (V)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
t <sub>PLH</sub> ,	Propagation	4.5		1.6		1.8		2.0		2.1		2.3	nS
t <sub>PHL</sub> (Note 1)	Delay,	3.3		1.7		1.9		2.1		2.3		2.6	
	A <sub>n</sub> to B <sub>n</sub>	2.8		1.9		2.1		2.3		2.5		2.8	
		1.8		2.1		2.4		2.5		2.7		3.0	
		1.2		2.4		2.7		2.8		3.0		3.3	
t <sub>PZH</sub> ,	Output	4.5		2.6		3.8		4.0		4.1		4.3	nS
t <sub>PZL</sub> (Note 1)	OE to B <sub>n</sub>	3.3		3.7		3.9		4.1		4.3		4.6	
(Note I)		2.5		3.9		4.1		4.3		4.5		4.8	1
		1.8		4.1		4.4		4.5		4.7		5.0	
		1.2		4.4		4.7		4.8		5.0		5.3	
t <sub>PHZ</sub> ,	Output	4.5		2.6		3.8		4.0		4.1		4.3	nS
t <sub>PLZ</sub> (Note 1)	Disable,	3.3		3.7		3.9		4.1		4.3		4.6	
(Note I)	OE to B <sub>n</sub>	2.5		3.9		4.1		4.3		4.5		4.8	
		1.8		4.1		4.4		4.5		4.7		5.0	
		1.2		4.4		4.7		4.8		5.0		5.3	
t <sub>OSHL</sub> ,	Output to	4.5		0.15		0.15		0.15		0.15		0.15	nS
t <sub>OSLH</sub> (Note 1)	Output Skew,	3.3		0.15		0.15		0.15		0.15		0.15	
	Time	2.5		0.15		0.15		0.15		0.15		0.15	
		1.8		0.15		0.15		0.15		0.15		0.15	
		1.2		0.15		0.15		0.15		0.15		0.15	

1. Propagation delays defined per Figure 2.

CAPACITANCE

.w.D	Symbol	Parameter	Test Conditions	Typ (Note 2)	Unit
	C <sub>IN</sub>	Control Pin Input Capacitance	$V_{CCA}$ = $V_{CCB}$ = 3.3 V, $V_{I}$ = 0 V or $V_{CCA/B}$	3.5	pF
	C <sub>I/O</sub>	I/O Pin Input Capacitance	$V_{CCA}$ = $V_{CCB}$ = 3.3 V, $V_{I}$ = 0 V or $V_{CCA/B}$	5.0	pF
	C <sub>PD</sub>	Power Dissipation Capacitance	$V_{CCA}$ = $V_{CCB}$ = 3.3 V, $V_{I}$ = 0 V or $V_{CCA},f$ = 10 MHz	20	pF

2. Typical values are at  $T_A = +25^{\circ}C$ . 3.  $C_{PD}$  is defined as the value of the IC's equivalent capacitance from which the operating current can be calculated from:  $I_{CC(operating)} \cong C_{PD} \times V_{CC} \times f_{IN} \times N_{SW}$  where  $I_{CC} = I_{CCA} + I_{CCB}$  and  $N_{SW}$  = total number of outputs switching.

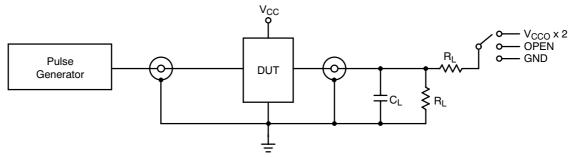
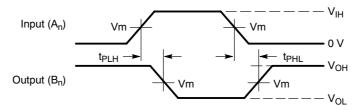
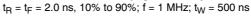


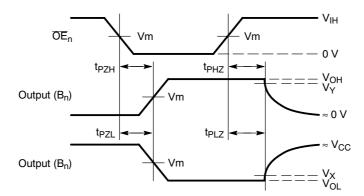
Figure 2. AC (Propagation Delay) Test Circuit

Test	Switch
t <sub>PLH</sub> , t <sub>PHL</sub>	OPEN
t <sub>PLZ</sub> , t <sub>PZL</sub>	V <sub>CCO</sub> x 2
t <sub>PHZ</sub> , t <sub>PZH</sub>	GND
$C_L$ = 15 pF or equivalent (include $R_L$ = 2 k $\Omega$ or equivalent $Z_{OUT}$ of pulse generator = 50 $\Omega$	es probe and jig capacitance)



Waveform 1 – Propagation Delays



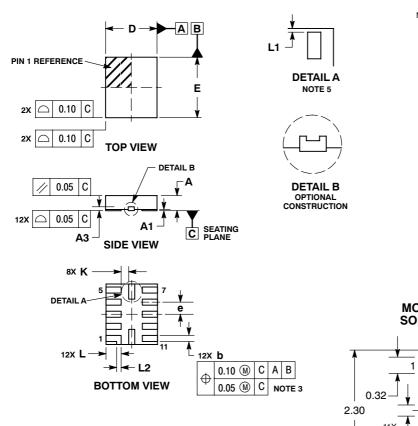


Waveform 2 – Output Enable and Disable Times  $t_R$  =  $t_F$  = 2.0 ns, 10% to 90%; f = 1 MHz;  $t_W$  = 500 ns

			V <sub>CC</sub>								
www.D	ataShe <b>syhbo</b> pm	3.0 V – 4.5 V	2.3 V – 2.7 V	1.65 V – 1.95 V	1.4 V – 1.6 V	0.9 V – 1.3 V					
	V <sub>mA</sub>	V <sub>CCA</sub> /2									
	V <sub>mB</sub>	V <sub>CCB</sub> /2									
	V <sub>X</sub>	V <sub>OL</sub> x 0.1									
	V <sub>Y</sub>	V <sub>OH</sub> x 0.9									

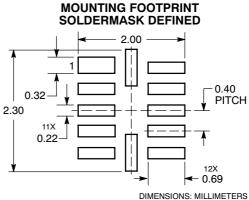
#### PACKAGE DIMENSIONS

UQFN12 1.7x2.0, 0.4P CASE 523AE-01 ISSUE A



- NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M. 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS 3. DIMENSION 6 APPLIES TO PLATED TERMINAL
- DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 MM FROM TERMINAL TIP.
- MOLD FLASH ALLOWED ON TERMINALS ALONG EDGE OF PACKAGE. FLASH 0.03 MAX ON BOTTOM SURFACE OF TERMINALS.
  DETAIL A SHOWS OPTIONAL
- 5. DETAIL A SHOWS OPTIONAL CONSTRUCTION FOR TERMINALS.

	MILLIMETERS	
DIM	MIN	MAX
Α	0.45	0.55
A1	0.00	0.05
A3	0.127 REF	
b	0.15	0.25
D	1.70 BSC	
E	2.00 BSC	
е	0.40 BSC	
K	0.20	
L	0.45	0.55
L1	0.00	0.03
L2	0.15 REF	



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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